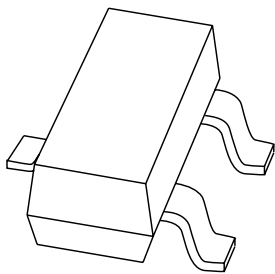


# DATA SHEET



**BF570**

**NPN medium frequency transistor**

Product specification  
Supersedes data of 2004 Jan 13

2004 Mar 15

# NPN medium frequency transistor

**BF570**

## FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 15 V)
- Low feedback capacitance (max. 2.2 pF).

## APPLICATIONS

- Monitors
- Battery equipped applications.

## DESCRIPTION

NPN transistor in a SOT23 plastic package.

## MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BF570	61* or B26

### Note

- \* = p : Made in Hong Kong.  
 \* = t : Made in Malaysia.  
 \* = W : Made in China.

## PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

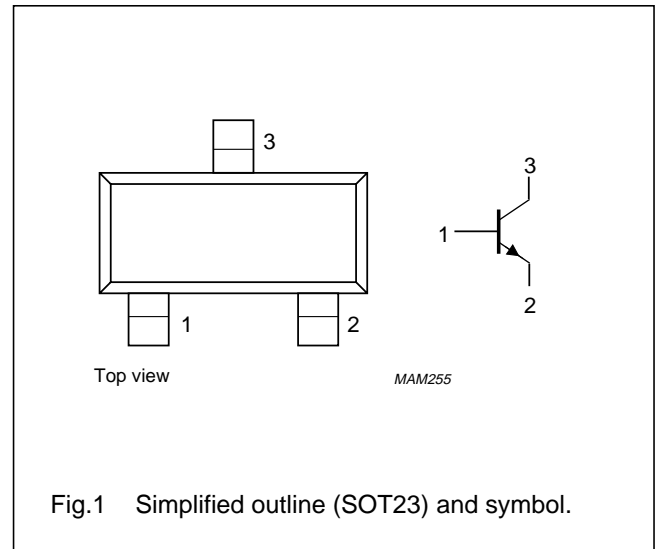


Fig.1 Simplified outline (SOT23) and symbol.

## ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
BF570	–	plastic surface mounted package; 3 leads	SOT23

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	40	V
$V_{CEO}$	collector-emitter voltage	open base	–	15	V
$I_{CM}$	peak collector current		–	200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ }^{\circ}\text{C}$	–	250	mW
$h_{FE}$	DC current gain	$I_C = 10\text{ mA}; V_{CE} = 1\text{ V}$	40	–	
$f_T$	transition frequency	$I_C = 40\text{ mA}; V_{CE} = 10\text{ V}; f = 100\text{ MHz}$	490	–	MHz

## NPN medium frequency transistor

BF570

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	40	V
$V_{CEO}$	collector-emitter voltage	open base	–	15	V
$V_{EBO}$	emitter-base voltage	open collector	–	4.5	V
$I_C$	collector current (DC)		–	100	mA
$I_{CM}$	peak collector current		–	200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$	–	250	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C
$T_{amb}$	operating ambient temperature		–65	+150	°C

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	500	K/W

**CHARACTERISTICS** $T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CBO}$	collector cut-off current	$I_E = 0\text{ A}; V_{CB} = 20\text{ V}$	–	–	400	nA
		$I_E = 0\text{ A}; V_{CB} = 20\text{ V}; T_j = 125\text{ °C}$	–	–	30	$\mu\text{A}$
$I_{EBO}$	emitter cut-off current	$I_C = 0\text{ A}; V_{EB} = 2\text{ V}$	–	–	100	nA
$h_{FE}$	DC current gain	$I_C = 10\text{ mA}; V_{CE} = 1\text{ V}$	40	–	–	
$C_{re}$	feedback capacitance	$I_C = 0\text{ A}; V_{CE} = 10\text{ V}; f = 1\text{ MHz}$	–	1.6	2.2	pF
$f_T$	transition frequency	$I_C = 10\text{ mA}; V_{CE} = 10\text{ V}; f = 100\text{ MHz}$	500	–	–	MHz
		$I_C = 40\text{ mA}; V_{CE} = 10\text{ V}; f = 100\text{ MHz}$	490	–	–	MHz

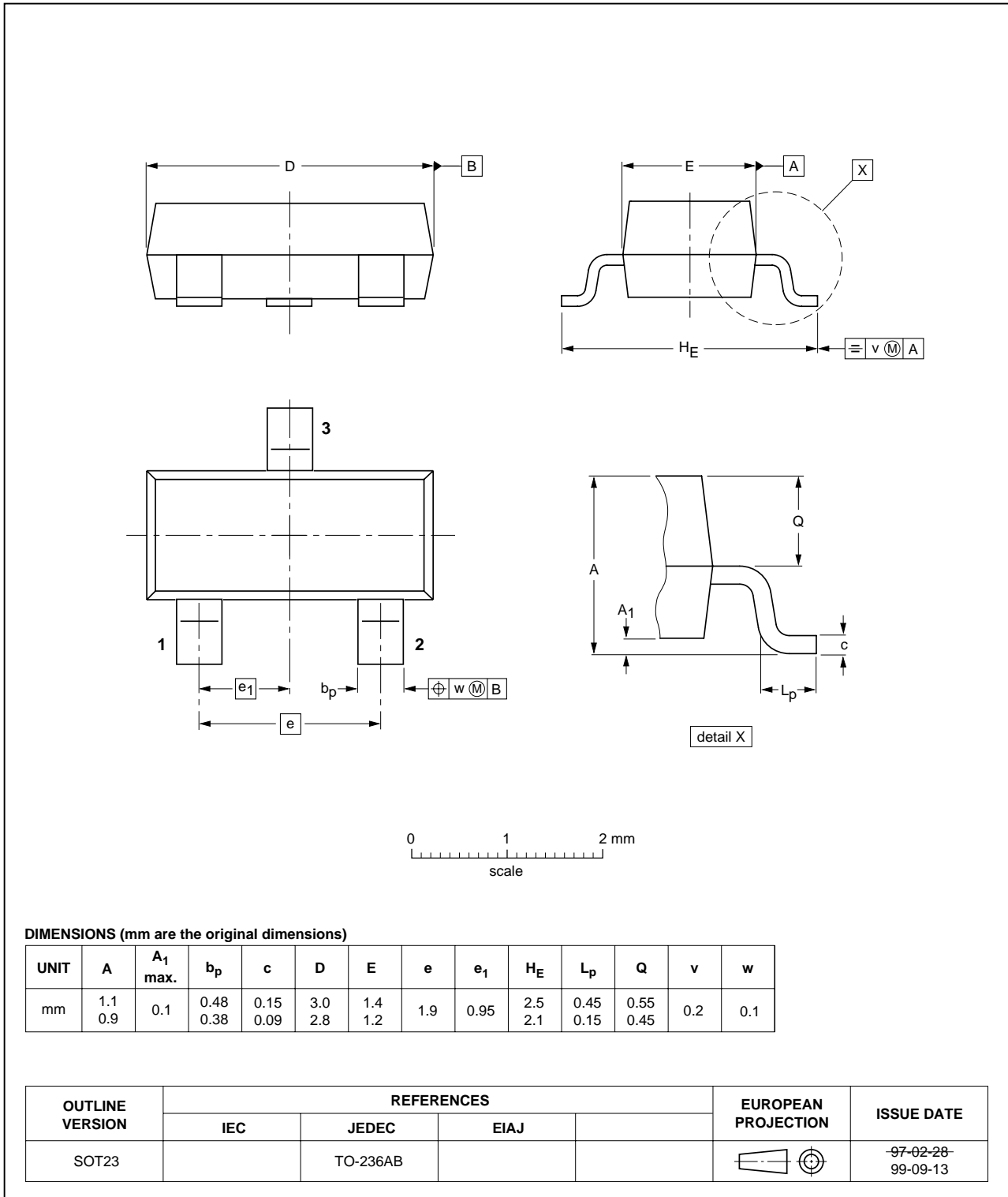
NPN medium frequency transistor

BF570

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



## NPN medium frequency transistor

BF570

## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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